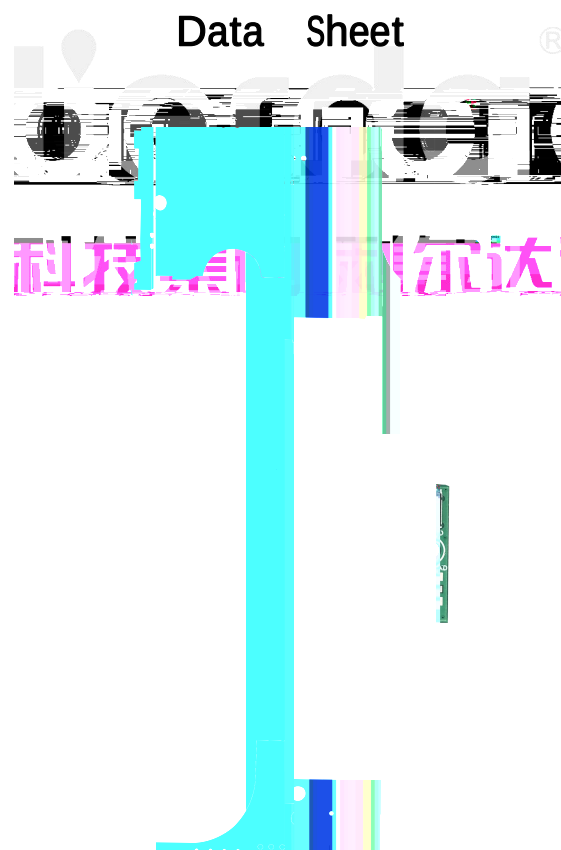


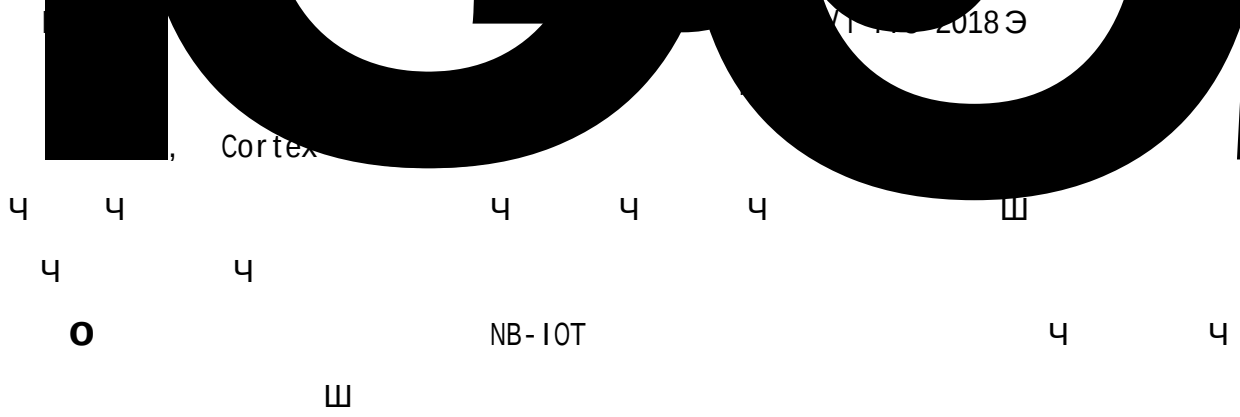


LSD3SWM-0110000000
NB-IOT
Rev01

科技集团 利尔达



1.



2.



4.

1		-25℃ 60℃	℃	-10℃ 40℃
2		-30℃ 70℃	℃	-25℃ 55℃
3		PCBA: 10%~90%()	%RH	GB 778.1-2018-T 5.4.5
4		¥0.01	m	
5		2.8V-3.6V	V	
6		Ů300	mA	
7		Ů25	í A	
8		50	mm	
9	NB-IOT	23dBm ¥2dBm	dBm	B5 4 B8
10	NB-IOT	0.2mAh/		RSRP -110dBm SNR 0dB
11			-	®

5.

1		科技集团 利尔达
2		RTC MCU
3		4 3
4		NB-IOT
5		36 180 31
6		
7		
8	NB-IOT	NB-IOT
9		
10		

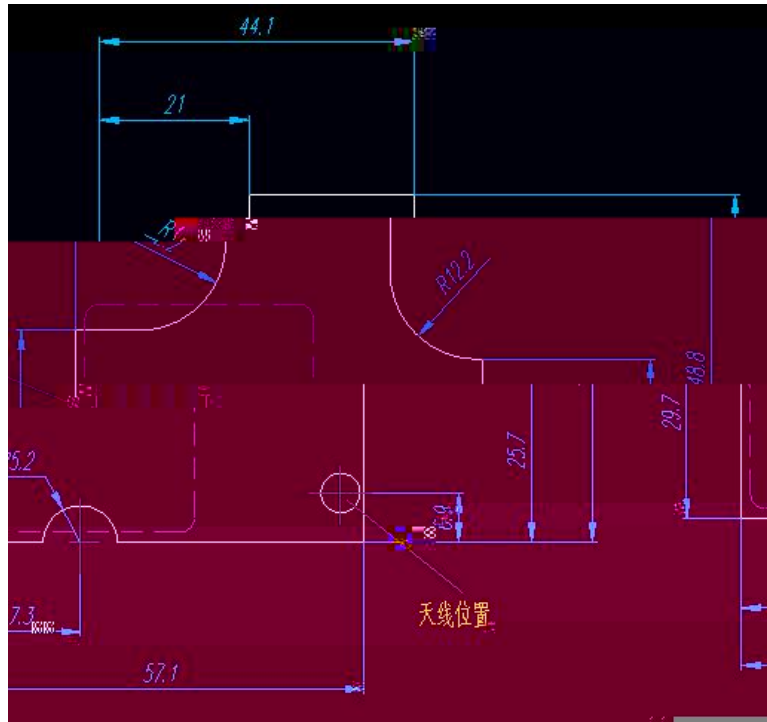
11

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12



7.



:mm

8.

科技集团 利尔达

1. 3

IO GB/T 778-2018

2. 3

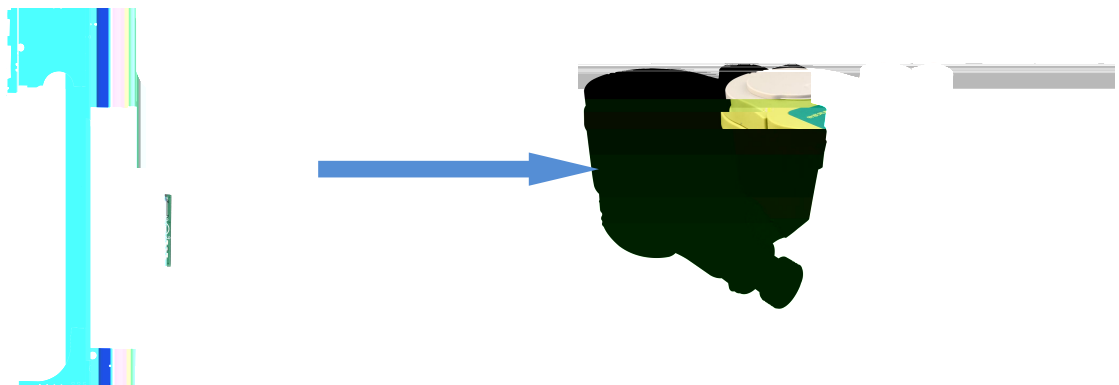
IO CJ/T224 -2012

3. 3

IO CJ266-2008

9.

9.1.



W

W

4

W

9.2.



4

4

W

NB-10T

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